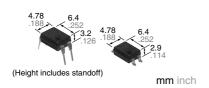
anasonic





4-pin high capacity of 1.1A, I/O isolation voltage of 5,000V

Photo MOS® GU 1 Form A High Capacity (AQY212GH)



FEATURES

- 1. Greatly increased capacity Continuous load current: 1.1A
- 2. Reinforced insulation I/O isolation voltage: 5,000 Vrms
- 3. Compact 4-pin DIP type
- 4. The improved performance relative to mercury or mechanical relays

TYPICAL APPLICATIONS

- Measuring instruments
- Security and disaster-preventing system: use in I/O for alarm and security devices, etc.

RoHS compliant

TYPES

	Output rating*			Par	Dealing growth.			
			Through hole terminal	Through hole terminal Surface-mount terminal				Packing quantity
	Load Load	Tube packing style		Tape and reel packing style				
	Load Load voltage current			Picked from the 1/2-pin side	Picked from the 3/4-pin side	Tube	Tape and reel	
AC/DC dual use	60 V	1.1 A	AQY212GH	AQY212GHA	AQY212GHAX	AQY212GHAZ	1 tube contains 100 pcs. 1 batch contains 1,000 pcs.	1,000 pcs.

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the three initial letters of the part number "AQY", the surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

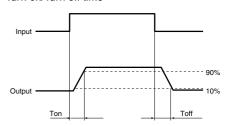
	Item	Symbol	AQY212GH(A)	Remarks
	LED forward current	l _F	50 mA	
I	LED reverse voltage	VR	5 V	
Input	Peak forward current	IFP	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW	
	Load voltage (peak AC)	VL	60 V	
Outout	Continuous load current	l _L	1.1 A	Peak AC, DC
Output	Peak load current	Ipeak	3.0 A	100ms (1 shot), V _L = DC
	Power dissipation	Pout	500 mW	
Total power dissipation)	P⊤	550 mW	
I/O isolation voltage		Viso	5,000 Vrms	
Ambient temperature	Operating	Topr	−40 to +85°C −40 to +185°F	(Non-icing at low temperatures)
	Storage	T _{stg}	-40 to +100°C -40 to +212°F	

-1-

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQY212GH(A)	Condition	
Input	LED operate current	Typical	Fon	1.1 mA	IL = 100mA	
	LED operate current	Maximum] IFon	3 mA	IL = TOOMA	
	LED turn off current	Minimum	Foff	0.3 mA	IL = 100mA	
	LED turn on current	Typical	IFoff	1.0 mA	IL = TOOTIA	
	LED dropout voltage	Typical	VF	1.32 V (1.14 V at I _F = 5 mA)	I _F = 50 mA	
	LLD dropout voltage	Maximum	VF	1.5 V	IF = 50 IIIA	
Output	On resistance	Typical	Ron	0.34 Ω	I _F = 5 mA I _L = Max.	
	On resistance	Maximum	H ion	0.7 Ω	Within 1 s	
	Off state leakage current	Maximum	Leak	1 μΑ	I _F = 0 mA V _L = Max.	
	Turn on time*	Typical	Ton	1.3 ms	I _F = 5 mA I _L = 100 mA	
	rum on time	Maximum	Ion	5.0 ms	V _L = 10 V	
Transfer	Turn off time*	Typical	- T _{off}	0.1 ms	I _F = 5 mA I _L = 100 mA	
characteristics	rum on ume	Maximum	loff	0.5 ms	V _L = 10 V	
	1/0	Typical		0.8 pF	f = 1 MHz	
	I/O capacitance	Maximum	Ciso	1.5 pF	V _B = 0 V	
	Initial I/O isolation resistance Minimum		Riso	1,000 ΜΩ	500 V DC	

*Turn on/Turn off time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

	em	Symbol	Min.	Max.	Unit
LED	lF	5	30	mA	
AQY212GH(A)	Load voltage (Peak AC)	VL	_	48	V
AQ1212GH(A)	Continuous load current	l _L	_	1.1	Α

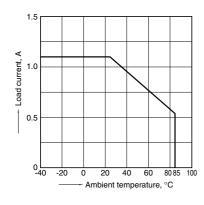
■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

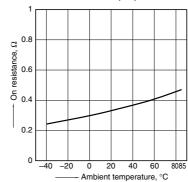
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C



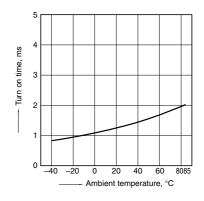
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 5 mA; Load voltage: Max. (DC) Continuous load current: Max.(DC)



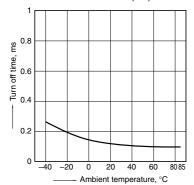
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)

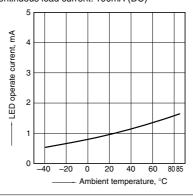


4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



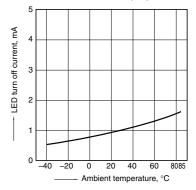
5. LED operate current vs. ambient temperature characteristics Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



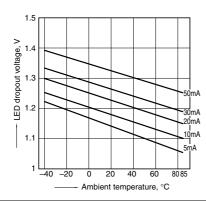
6. LED turn off current vs. ambient temperature characteristics

Load voltage: 10 V (DC);

Continuous load current: 100mA (DC)

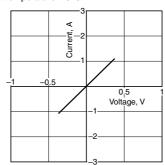


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



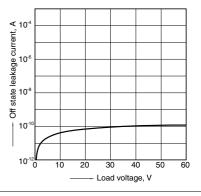
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



9. Off state leakage current vs. load voltage characteristics

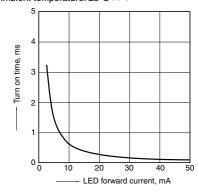
Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: 10 V (DC);

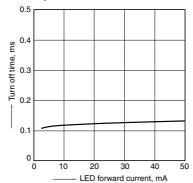
Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°



11. Turn off time vs. LED forward current characteristics

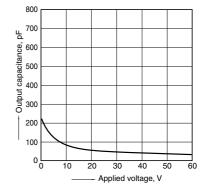
Measured portion: between terminals 3 and 4; Load voltage: 10 V (DC);

Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



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